/ Descriptions

TO-251 NPN Silicon NPN transistor in a TO-251 Plastic Package.

/ Features

$V_{CE(sat)}$,h_{FE}

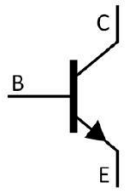
Low saturation voltage, excellent h_{FE} linearity and high h_{FE}.

/ Applications

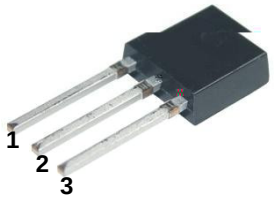
3 , ,

Output stage of 3 watts audio amplifier, voltage regulator, DC-DC converter and relay driver.

/ Equivalent Circuit



/ Pinning



PIN1 Base PIN 2 Collector PIN 3 Emitter

/ h_{FE} Classifications & Marking

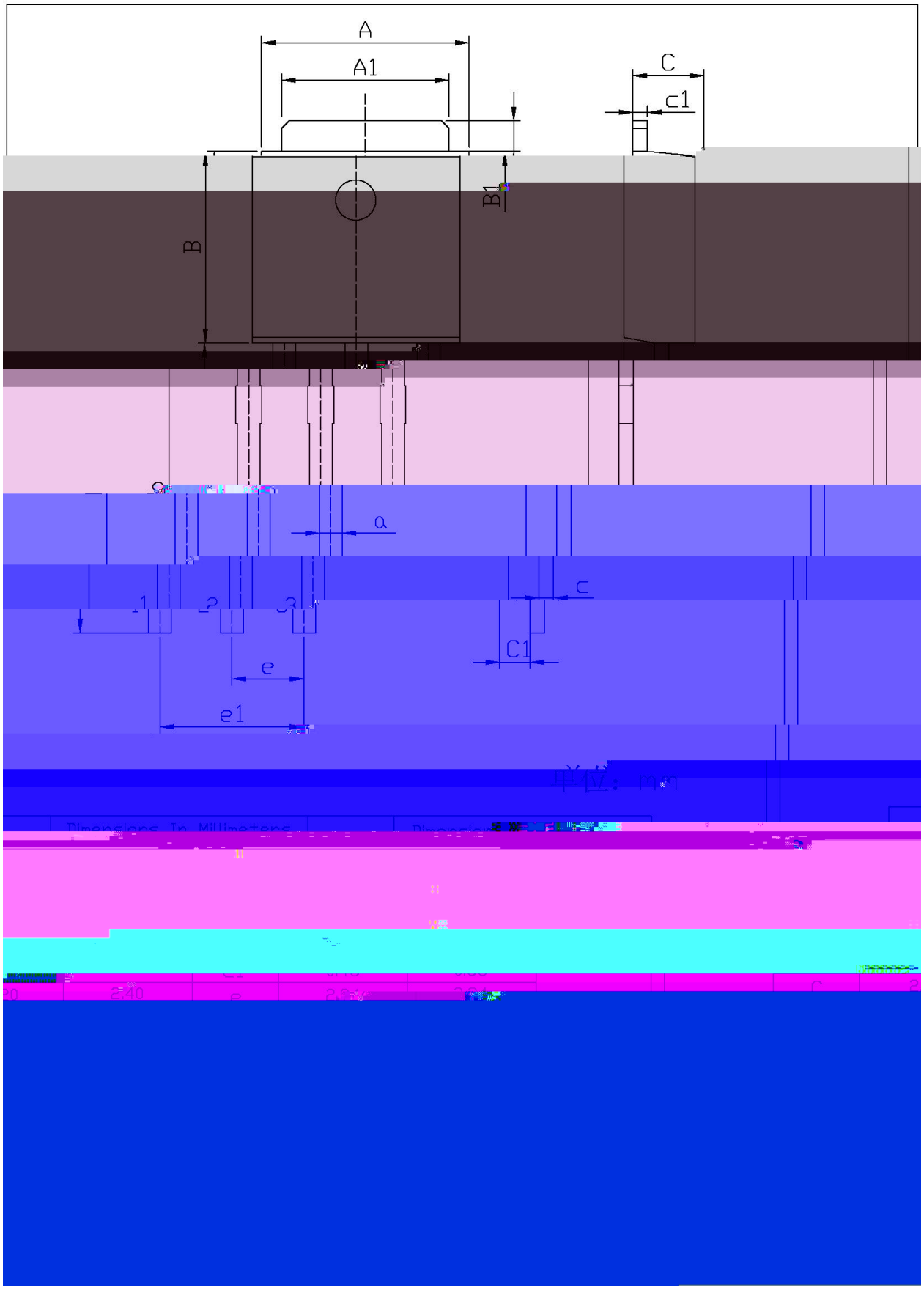
h_{FE} Classifica0.070cions Symbol	R	Q	P	E
h_{FE} Range	60 120	100 200	160 320	200 400

Parameter	Symbol

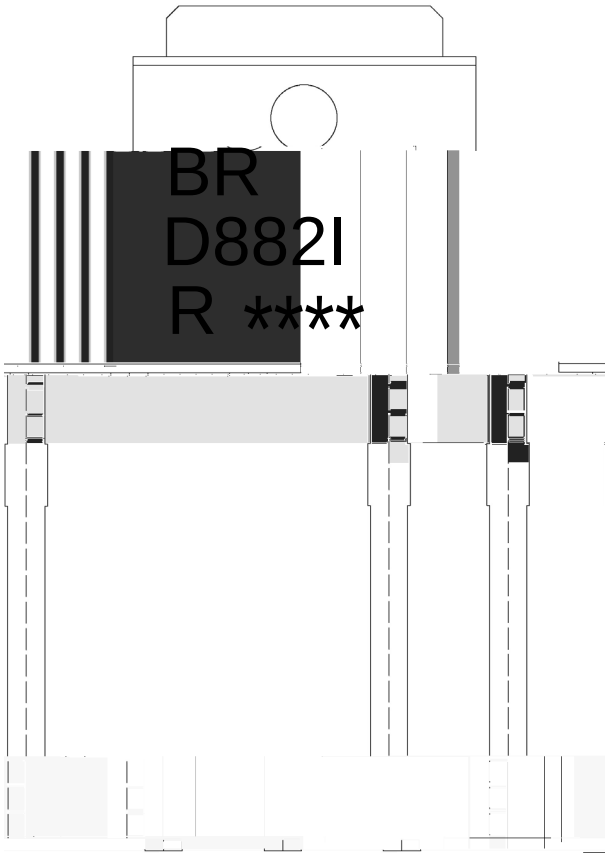
/ Electrical Characteristic Curve



/ Package Dimensions



/ Marking Instructions



BR

D882I

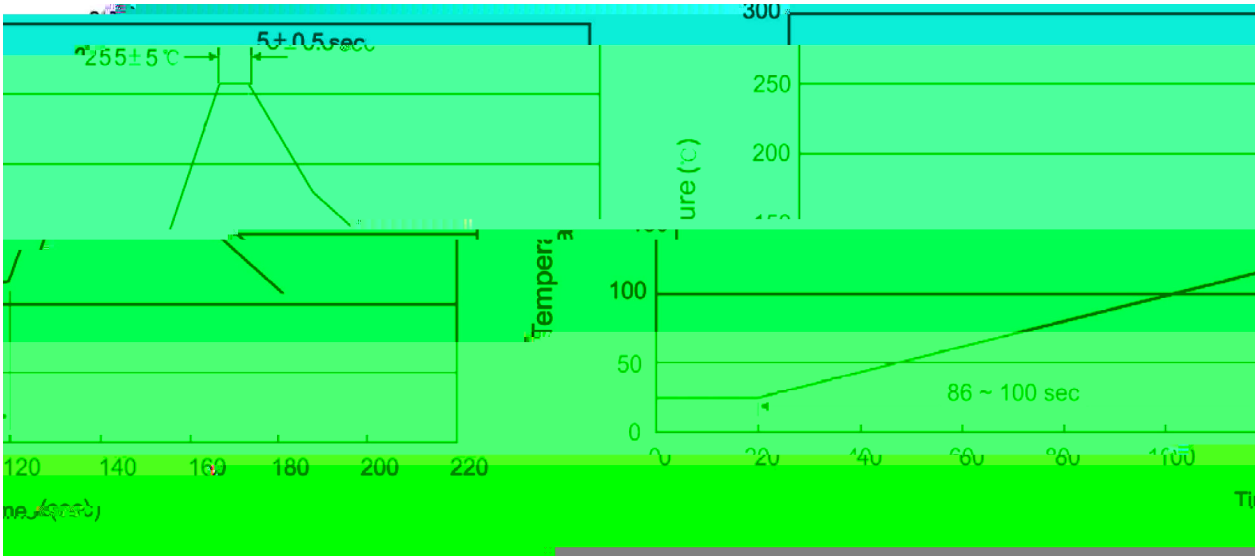
R: h_{FE}

****

Note:

BR:	Company Code
D882I:	Product Type.
R:	h_{FE} Classifications Symbol
****:	Lot No. Code, code change with Lot No.

( ) / Temperature Profile for Dip Soldering(Pb-Free)



					Note:
1		25 150		60 90sec;	1.Preheating:25~150 , Time:60~90sec.
2		255±5		5±0.5sec;	2.Peak Temp.:255±5 , Duration:5±0.5sec.
3			2 10	/sec.	3. Cooling Speed: 2~10 /sec.

/ Resistance to Soldering Heat Test Conditions

270±5	10±1 sec.	Temp.:270±5	Time:10±1 sec

/ Packaging SPEC.

/ BULK

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm^3)		
	Units/Bag 只/袋	Bags/Inner Box 袋/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Bag 袋	Inner Box 盒	Outer Box 箱
TO-251	1,000	10	10,000	5	50,000	135×190	237×172×102	560×245×195

/ TUBE

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm^3)		
	Units/Tube 只/套管	Tubes/Inner Box 套管/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Tube 套管	Inner Box 盒	Outer Box 箱
TO-251/252	75	48	3,600	5	18,000	526×20.5×5.25	555×164×50	575×290×180

/ Notices